

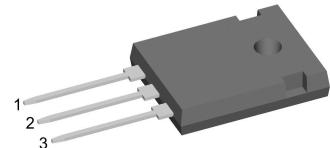
# Thyristor

$V_{RRM}$  = 1600 V  
 $I_{TAV}$  = 40 A  
 $V_T$  = 1,21 V

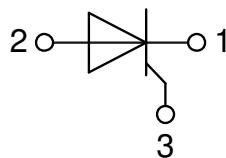
## Single Thyristor

### Part number

**CMA40E1600HR**



Backside: isolated



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: ISO247

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- High creepage distance between terminals

### Terms & Conditions of usage:

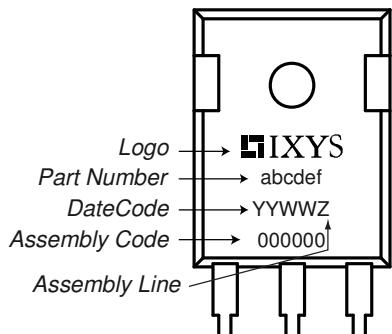
The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you. Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;
- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Thyristor			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1700	V
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage	$T_{VJ} = 25^\circ C$			1600	V
$I_{R/D}$	reverse current, drain current	$V_{R/D} = 1600 V$ $V_{R/D} = 1600 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		50 5	$\mu A$ mA
$V_T$	forward voltage drop	$I_T = 40 A$ $I_T = 80 A$ $I_T = 40 A$ $I_T = 80 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		1,23 1,52 1,21 1,59	V V V V
$I_{TAV}$	average forward current	$T_C = 90^\circ C$	$T_{VJ} = 150^\circ C$		40	A
$I_{T(RMS)}$	RMS forward current	180° sine			63	A
$V_{T0}$	threshold voltage	$r_T$ slope resistance } for power loss calculation only	$T_{VJ} = 150^\circ C$		0,81	V
	slope resistance				9,8	$m\Omega$
$R_{thJC}$	thermal resistance junction to case				0,8	K/W
$R_{thCH}$	thermal resistance case to heatsink				0,25	K/W
$P_{tot}$	total power dissipation		$T_C = 25^\circ C$		155	W
$I_{TSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 150^\circ C$ $V_R = 0 V$		550 595 470 505	A A
$I^2t$	value for fusing	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$	$T_{VJ} = 45^\circ C$ $V_R = 0 V$ $T_{VJ} = 150^\circ C$ $V_R = 0 V$		1,52 1,48 1,11 1,06	kA <sup>2</sup> s kA <sup>2</sup> s kA <sup>2</sup> s kA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400 V$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ C$		26	pF
$P_{GM}$	max. gate power dissipation	$t_p = 30 \mu s$ $t_p = 300 \mu s$	$T_C = 150^\circ C$		10 5 0,5	W W W
$P_{GAV}$	average gate power dissipation					
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 150^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 120 A$ $t_p = 200 \mu s; di_G/dt = 0,3 A/\mu s;$ $I_G = 0,3 A; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 40 A$			150	A/ $\mu s$
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$T_{VJ} = 150^\circ C$		1000	V/ $\mu s$
$V_{GT}$	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		1,5 1,6	V V
$I_{GT}$	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$		50 80	mA mA
$V_{GD}$	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^\circ C$		0,2	V
$I_{GD}$	gate non-trigger current				5	mA
$I_L$	latching current	$t_p = 10 \mu s$ $I_G = 0,3 A; di_G/dt = 0,3 A/\mu s$	$T_{VJ} = 25^\circ C$		125	mA
$I_H$	holding current	$V_D = 6 V$ $R_{GK} = \infty$	$T_{VJ} = 25^\circ C$		100	mA
$t_{gd}$	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0,3 A; di_G/dt = 0,3 A/\mu s$	$T_{VJ} = 25^\circ C$		2	$\mu s$
$t_q$	turn-off time	$V_R = 100 V; I_T = 40 A; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 125^\circ C$ $di/dt = 10 A/\mu s$ $dv/dt = 20 V/\mu s$ $t_p = 200 \mu s$			150	$\mu s$

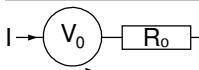
Package ISO247			Ratings		
Symbol	Definition	Conditions	min.	typ.	max.
$I_{RMS}$	RMS current	per terminal			70 A
$T_{VJ}$	virtual junction temperature		-55		150 °C
$T_{op}$	operation temperature		-55		125 °C
$T_{stg}$	storage temperature		-55		150 °C
<b>Weight</b>				6 g	
$M_d$	mounting torque		0,8		1,2 Nm
$F_c$	mounting force with clip		20		120 N
$d_{Spp/App}$	creepage distance on surface / striking distance through air	terminal to terminal	2,7		mm
$d_{Spb/Apb}$		terminal to backside	4,1		mm
$V_{ISOL}$	isolation voltage	$t = 1$ second $t = 1$ minute	3600 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000	V V

**Product Marking****Part description**

C = Thyristor (SCR)  
 M = Thyristor  
 A = (up to 1800V)  
 40 = Current Rating [A]  
 E = Single Thyristor  
 1600 = Reverse Voltage [V]  
 HR = ISO247 (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CMA40E1600HR	CMA40E1600HR	Tube	30	515435

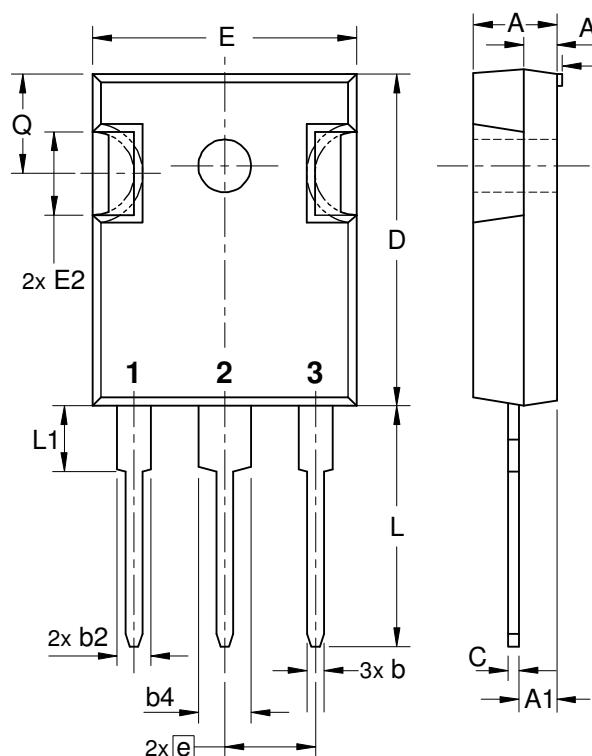
Similar Part	Package	Voltage class
CLA40E1200HR	ISO247 (3)	1200

**Equivalent Circuits for Simulation***\* on die level* $T_{VJ} = 150$  °C

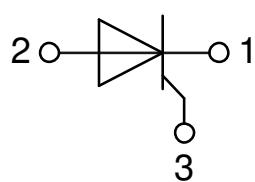
Thyristor

$V_{0\max}$  threshold voltage 0,81 V  
 $R_{0\max}$  slope resistance \* 7,2 mΩ

## Outlines ISO247



Dim.	Millimeter		Inches	
	min	max	min	max
A	4.70	5.30	0.185	0.209
A1	2.21	2.59	0.087	0.102
A2	1.50	2.49	0.059	0.098
A3	typ. 0.05		typ. 0.002	
b	0.99	1.40	0.039	0.055
b2	1.65	2.39	0.065	0.094
b4	2.59	3.43	0.102	0.135
c	0.38	0.89	0.015	0.035
D	20.79	21.45	0.819	0.844
D1	typ. 8.90		typ. 0.350	
D2	typ. 2.90		typ. 0.114	
D3	typ. 1.00		typ. 0.039	
E	15.49	16.24	0.610	0.639
E1	typ. 13.45		typ. 0.530	
E2	4.31	5.48	0.170	0.216
E3	typ. 4.00		typ. 0.157	
e	5.46	BSC	0.215	BSC
L	19.80	20.30	0.780	0.799
L1	-	4.49	-	0.177
Ø P	3.55	3.65	0.140	0.144
Q	5.38	6.19	0.212	0.244
S	6.14	BSC	0.242	BSC



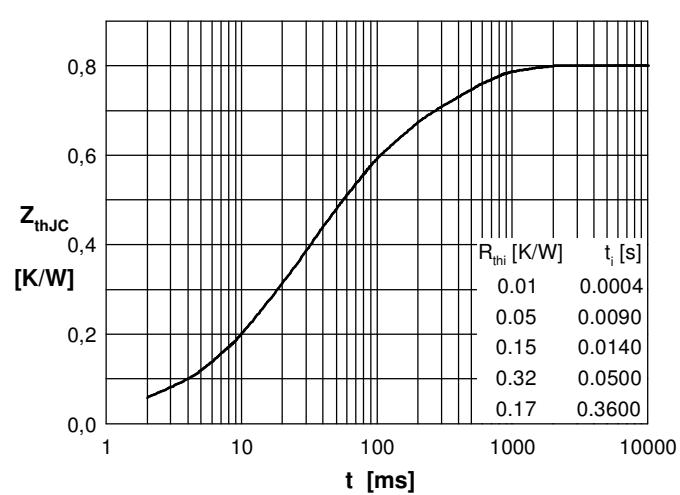
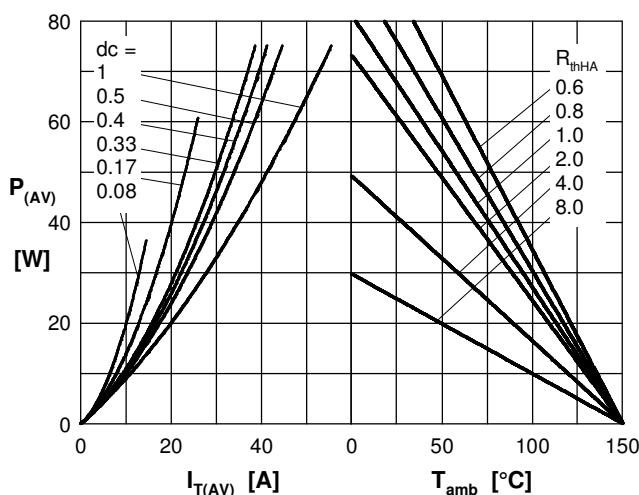
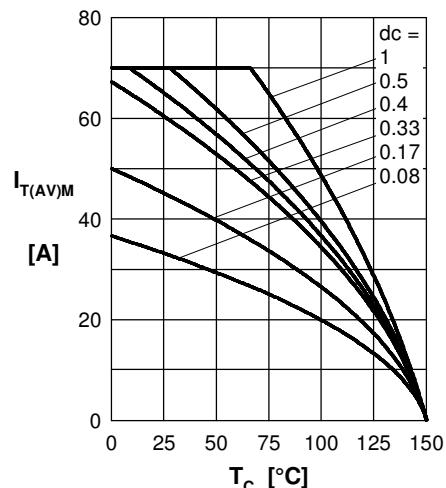
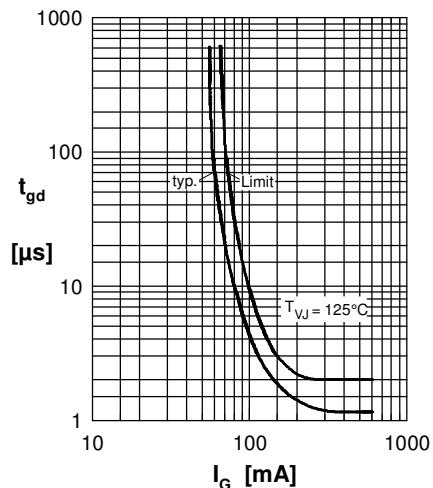
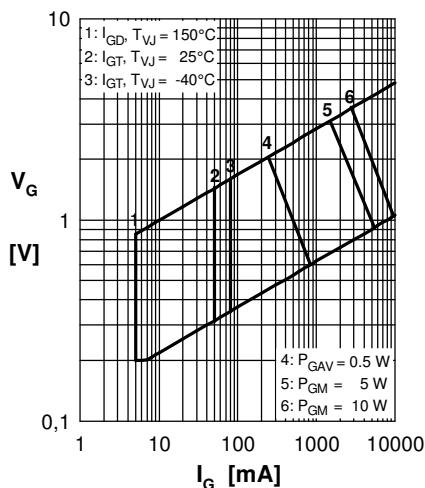
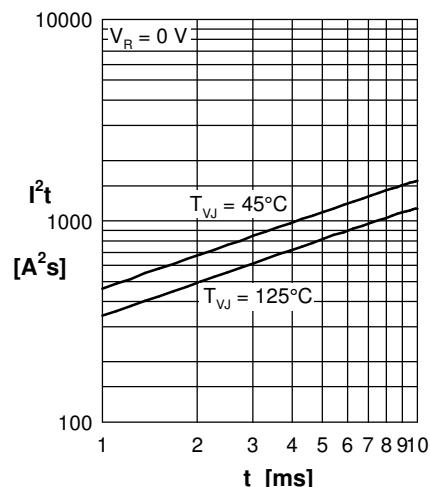
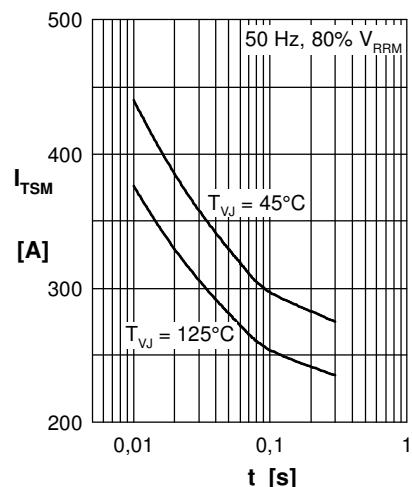
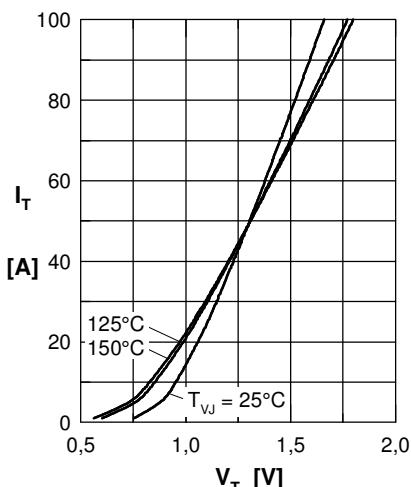
**Thyristor**

Fig. 7a Power dissipation versus direct output current  
Fig. 7b and ambient temperature

Fig. 8 Transient thermal impedance